NSN 5961-00-175-9206

Transistor - Page 1 of 2



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Inclosure Material:

Metal and ceramic

Overall Length:

0.270 inches

Overall Height:

0.320 inches

Overall Diameter:

0.360 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Emitter

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

90.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

3.30 amperes all primaries

Power Rating Per Characteristic:

70.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

NSN 5961-00-175-9206 Transistor - Page 2 of 2

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